



1N4148W

SMALL SIGNAL SWITCHING DIODE

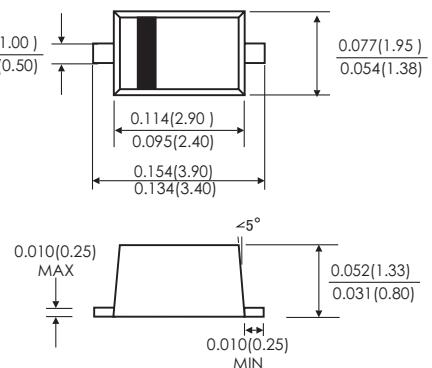
## FEATURES

- Silicon epitaxial planar diode
- Fast switching diode
- 500mW power dissipation
- This diode is also available in other case styles including: the DO-35 case with the type designation 1N4148, the MiniMelf case with the type designation LL4148, the MicroMelf case with the type designation MCL4148, the SOD-323 case with the type designation 1N4148WS, the SOD-523 case with the type designation 1N4148WT.



## MECHANICAL DATA

- Case: SOD-123FL plastic case
- Weight: Approx. 0.01 gram



Dimensions in inches and (millimeters)

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified)

	Symbols	Value	Units
DC Blocking Voltage	V <sub>R</sub>	75	Volts
Non-Repetitive Peak Reverse Voltage	V <sub>RM</sub>	100	Volts
Average rectified current, Half wave rectification with Resistive load at T <sub>A</sub> =25°C and f ≥50Hz	I <sub>AV</sub>	150	mA
Non-Repetitive Peak Forward Surge Current @t=1.0s	I <sub>FSM</sub>	500	mA
Power dissipation at T <sub>A</sub> =25°C	P <sub>tot</sub>	400	mW
Junction temperature	T <sub>J</sub>	150	°C
Storage temperature range	T <sub>STG</sub>	-65 to +150	°C

## ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified)

	Symbol	Min.	Typ.	Max.	Units
Forward voltage at I <sub>F</sub> =10mA	V <sub>F</sub>			1	Volts
Leakage current at V <sub>R</sub> =20V at V <sub>R</sub> =75V at V <sub>R</sub> =20V, T <sub>J</sub> =150°C	I <sub>R</sub>			25 5 50	nA μA μA
Junction capacitance at V <sub>R</sub> =V <sub>F</sub> =0V	C <sub>J</sub>			4	pF
Voltage rise when switching on tested with 50mA pulse t <sub>r</sub> =0.1μs, Rise time<30μs, f <sub>p</sub> =5 to 100kHz	V <sub>fr</sub>			2.5	Volts
Reverse recovery time from I <sub>F</sub> =10mA to I <sub>R</sub> =1mA, V <sub>R</sub> =6V, R <sub>L</sub> =100Ω	t <sub>rr</sub>			4	ns
Thermal resistance junction to ambient	R <sub>θJA</sub>		312		°C/W
Rectification efficiency at f=100MHz, V <sub>RF</sub> =2V	η	0.45			

## RATINGS AND CHARACTERISTIC CURVES 1N4148W

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FIG 1-FORWARD CHARACTERISTICS

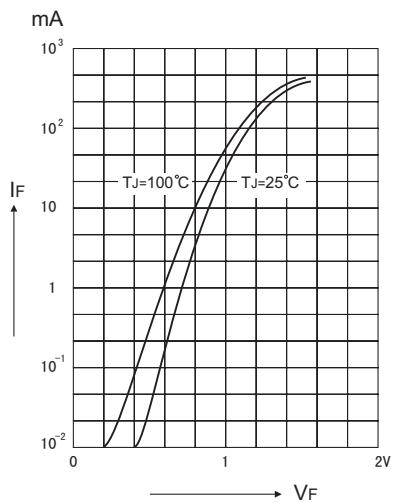


FIG 2: DYNAMIC FORWARD RESISTANCE  
VERSUS FORWARD CURRENT

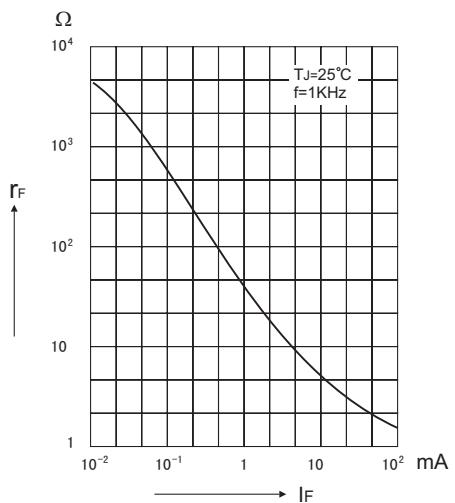


FIG 3-ADMISSIBLE POWER DISSIPATION  
VERSUS AMBIENT TEMPERATURE

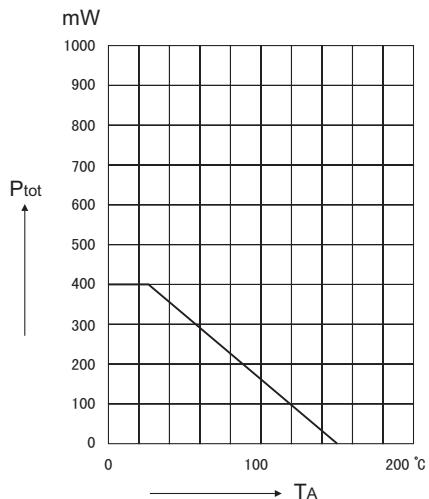
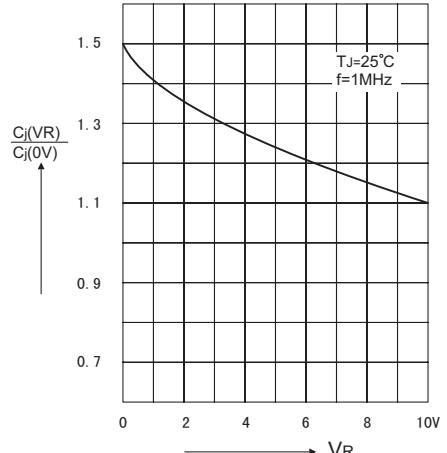


FIG. 4-RELATIVE CAPACITANCE VERSUS  
VOLTAGE



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FIG.5 RECTIFICATION EFFICIENCY MEASUREMENT CIRCUIT

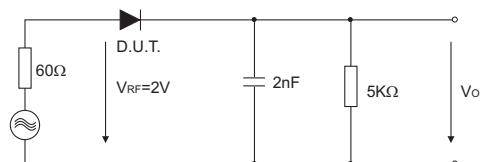


FIG 6: LEAKAGE CURRENT VERSUS JUNCTION TEMPERATURE

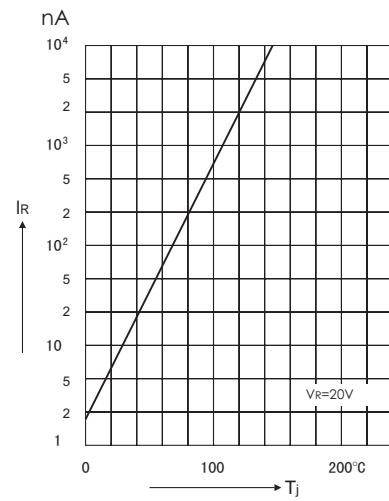


FIG 7: ADMISSIBLE REPETITIVE PEAK FORWARD CURRENT VERSUS PULSE DURATION

